micro PMAT® HAMAMATSU

MICRO PMT ASSEMBLY MICRO PMT MODULES MICRO PMT PHOTON COUNTING HEAD



World's smallest and lightest photomultiplier tube* Micro PMT[™]

asv

* By our research (as of December 2015)

mass produce Micro PMT can be produced in high volume while still maintaining high reliability and performance. What makes this possible is overall integrated usage of our in-house advanced technologies for MEMS (micro-electro-mechanical systems), semiconductor manufacturing, electron trajectory design, vacuum sealed packaging, and vacuum processing. **High shock** resistance Tiny dimensions Micro PMT devices offer strong shock Micro PMT has a three-layer resistance since anodic bonding by structure where a silicon MEMS technology is utilized to join substrate is sandwiched the silicon substrate to the glass between two glass substrates. substrates. This high cushioning or Utilizing only three components mic shock resistance makes them ideal gives tiny dimensions for developing high-performance, impossible up until now. hand-held testing and analysis devices. Customizing **High sensitivity** support and fast response Feel free to consult with us on Micro PMT utilizes the same high customizing to match customer precision structure for electrode usage conditions and SILLE arrangement as conventional environments. PMTs and so provides the high sensitivity and fast response needed from a PMT.

Full-scale Micro PMT image!



Micro PMT works on the same vacuum tube technology and principle as conventional PMTs and so can deliver the same performance as conventional PMT yet in a compact and light-weight unit.

Micro PMT internal structure



What is a PMT (photomultiplier tube)?

The PMT is a photosensor delivering superb high sensitivity and response speed compared with other types of photosensors. The PMT makes use of the secondary emission effect for electron multiplication and so achieves extremely high sensitivity and low noise compared to other photosensors currently in use to measure UV light, visible light, and near-infrared light. These features allow the PMT to be used in a broad range of applications including high-performance medical equipment and environmental monitors, etc.

Medical care

Medical diagnosis in the home or at the bedside

Bringing high-tech closer to the patient via compact and portable medical devices

Tests and inspections normally held in examination rooms or labs can now be made in emergency rooms or small clinics by using the advantages offered by Micro PMT. Performing sophisticated exams in the home could also allow detecting major diseases while still in their early stage. This means the Micro PMT could prove ideal not only for early stage disease diagnosis but also daily health care management.

Measurement

Making environmental pollution measurements on an individual or regional scale

Measurements under various environments and any type of location

Micro PMT also proves ideal as a photosensor for environmental monitoring tasks. Environmental problems including abnormal weather phenomenon and widescale natural disasters are recently occurring at places all around the world. If compact measurement devices were readily available, then environmental phenomena could be quickly detected at diverse locations to keep damage and losses to a be minimum.

µPMT® PRODUCT CONFIGURATION

	Assembly type	Module type					
Basic configration	Micro PMT + Divider circuit	Micro PMT + Divider circuit + High voltage power supply circuit					
Additional function		Current output		Voltage output	Photon counting		
Appearance	H12400 series	H14066 series	H12402/H12403 series	H12404/H12405 series	H12406 series		
Spectral response (nm)	300 to 650 300 to 850 300 to 920	300 to 650 300 to 850	300 to 650 300 to 850 300 to 920	300 to 650 300 to 850 300 to 920	300 to 650 300 to 850 300 to 920		

MICRO PMT ASSEMBLY H12400 SERIES

The H12400 series is a high sensitivity photosensor that combines a Micro PMT with a voltage divider circuit. The H12400 series can be installed even in narrow spaces due to its small size.



PRODUCT VARIATIONS

Type No.	Spectral response	Photocathode material	Features
H12400-00-01	300 nm to 650 nm	Bialkali	for visible range
H12400-01-01	300 nm to 850 nm	Multialkali	for visible to near IR range
H12400-20-01	300 nm to 920 nm	Extended red multialkali	for visible to near IR range

SPECIFICATIONS

3 75	CIFICATIC	2 112					(at +25 °C)
	Para	meter		H12400-00-01	H12400-01-01	H12400-20-01	Unit
Peak sensi	tivity wavelength			43	20	630	nm
Window ma	aterial				$3(X) \times 1(Y)$		mm
Effective ar	ea				Borosilicate glass		_
Dynode nu	mber of stages				12		—
Maximum	Supply voltage	Between anode and c	athode		-1150		V
ratinge	Divider current				126		μA
Taunys	Average output s	signal current			5		μA
		iv dite d	Min.	50	100	300	
	Luminous sensit	nsitivity		80	200	400	μ _Α /im
Cathode	Blue sensitivity in	ndex (CS 5-58)	Тур.	8.0	—	—	-
	Red / White ratio		Тур.	—	0.2	0.45	_
Radiant sensitivity ^①		ty 1	Тур.	80	62	60	mA/W
		iv dite d	Min.	30	15	30	A/Im
	Luminous sensit	ivity	Тур.	160	70	100	Aviini
	Radiant sensitivi	ty 1	Тур.	1.6 × 10⁵	2.1 × 10 ⁴	1.5 × 104	A/W
Anode ²	Dark ourrant 3		Тур.	0.3 0.6			
			Max.	:	3 6		IIA
		Rise time	Тур.		1.2		
	Time response	Transit time	Тур.		8.0		ns
		T.T.S. 4	Тур.		1.3		
Gain [®] Typ		Тур.	2.0 × 10 ⁶	3.5 × 10⁵	2.5 × 10⁵	_	
Operating a	ambient temperatu	ire [©]		+5 to +50		°C	
Storage ter	nperature ⁵			-20 to +50			°C
Weight				11			g

①Measured at the peak sensitivity wavelength

③After 30 minutes storage in darkness

⑤No condensation

②Supply Voltage: -900 V

(4)T.T.S.=Transit Time Spread (FWHM)





MICRO PMT MODULE H14066 SERIES

The H14066 series is a high sensitivity photosensor module that contain a Micro PMT, a voltage divider circuit, and a highvoltage power supply circuit. This module pin output type can board mounting, which can be easily operated with a low voltage supply.



PRODUCT VARIATIONS

Type No.	Spectral response	Photocathode material	Features
H14066	300 nm to 650 nm	Bialkali	for visible range
H14066-01	300 nm to 850 nm	Multialkali	for visible to near IR range

SPECIFICATIONS

SPE	CIFICATIONS				(at +25 °C)
	Parameter		H14066	H14066-01	Unit
Peak sensi	tivity wavelength		42	20	nm
Effective a	rea		4(X) >	< 1(Y)	mm
Window ma	aterial		Borosilic	ate glass	
Dynode nu	mber of stages		1	0	
Input volta	је		+4.75 te	o +5.25	V
Maximum i	nput voltage		+5	5.5	V
Maximum i	nput current ^①		5	5	mA
Maximum a	average output signal current		Ę	5	μΑ
Maximum	control voltage		+1.	.15	V
Recommended control voltage adjustment range		+0.5 to +1.0	+0.5 to +1.1	V	
Control voltage input impedance			1		MΩ
	Luminous sensitivity	Min.	70	100	μA/lm
		Тур.	100	200	
Cathode	Blue sensitivity index (CS 5-58)	Тур.	11.5		
	Red / White ratio	Тур.	—	0.2	
	Radiant sensitivity 2	Тур.	93	62	mA/W
	Luminous sensitivity ³	Min.	30	15	A/Im
		Тур.	200	70	
Anode 2	Radiant sensitivity (2)(3)	Тур.	1.9 × 10⁵	2.2×10^{4}	A/W
	Dark current 34	Тур.	0.	.3	nA
		Max.		3	
	Time response Rise time	Тур.	1.	.2	ns
Gain		Тур.	2.0×10^{6}	3.5 × 10⁵	
Ripple nois	e 35 (peak to peak)	Max.	0.	.3	mV
Settling time ⁶ Max.		Max.	1	0	S
Operating	ambient temperature ®		+5 to +50		°C
Storage ter	mperature 🕐		-20 to	o +50	°C
Weight			1	0	g

①At +5 V input voltage, +0.9 V control voltage, and output current equal to dark current 2 Measured at the peak sensitivity wavelength

3+0.9 V control voltage (4) After 30 minutes storage in darkness.

(5)Cable RG-174/U, Cable length 450 mm, Load resistance=1 M Ω , Load capacitance=22 pF

6 The time required for the output to reach a stable level following a change in the control voltage from +1.0 V to + 0.5 V. ⑦No condensation

SPECTRAL RESPONSE







MICRO PMT MODULE H12402/H12403 SERIES

The H12402/H12403 series are high sensitivity photosensor modules that contain a Micro PMT, a voltage divider circuit, and a high-voltage power supply circuit. These modules can be easily operated with a low voltage supply.



▲Left: H12403 series Right: H12402 series

(at +25 °C)

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PRODUCT VARIATIONS

Type No.	Spectral response	Photocathode material	Features
H12402 / H12403	300 nm to 650 nm	Bialkali	for visible range
H12402-01 / H12403-01	300 nm to 850 nm	Multialkali	for visible to near IR range
H12402-20 / H12403-20	300 nm to 920 nm	Extended red multialkali	for visible to near IR range

SPECIFICATIONS

	Parameter		H12402 / H12403	H12402-01 / H12403-01	H12402-20 / H12403-20	Unit
Peak sensi	tivity wavelength		4	20	630	nm
Effective ar	ea			$3(X) \times 1(Y)$	I	mm
Window ma	aterial			Borosilicate glass		_
Dynode nu	mber of stages			12		—
Input voltag	je			+4.5 to +5.5		V
Maximum i	nput voltage			+5.5		V
Maximum i	nput current ^①			20		mA
Maximum a	average output signal current ^②			5		μA
Maximum o	control voltage			+1.15		V
Recommer	ded control voltage adjustment	range	+0.5 to +1.0	+0.5 t	o +1.1	V
Control vol	age input impedance		1			MΩ
		Min.	50	100	300	u A/Im
		Тур.	80	200	400	μΑνιπ
Cathode	Blue sensitivity index (CS 5-58)	Тур.	8.0	_		—
	Red / White ratio	Тур.		0.2	0.45	—
	Radiant sensitivity ³	Тур.	80	62	60	mA/W
	Luminous sensitivity	Min.	30	15	30	Δ/Im
		Тур.	160	70	100	7,111
Anode ²	Radiant sensitivity ³	Тур.	1.6 × 10⁵	2.1 × 10 ⁴	1.5 × 104	A/W
Anoue	Dark current ⁽⁴⁾	Тур.	C	.3	0.6	nΔ
		Max.		3	6	
	Time response Rise time	Тур.		1.2		ns
Gain ²		Тур.	2.0 × 10 ⁶	3.5 × 10⁵	2.5 × 10⁵	—
Ripple nois	e ^{©5} (peak to peak)	Max.		0.3		mV
Settling tim	e ®	Max.	10			S
Operating a	ambient temperature $^{\textcircled{O}}$		+5 to +50			°C
Storage ter	nperature 7			-20 to +50		°C
Weight		Тур.	42 (H1	2402 series), 52 (H12403	series)	g

①At +5 V input voltage, +0.9 V control voltage, and output current equal to dark current

2+0.9 V control voltage

3 Measured at the peak sensitivity wavelength

4 After 30 minutes storage in darkness.

 $\overline{5}$ Cable RG-174/U, Cable length 450 mm, Load resistance=1 M Ω , Load capacitance=22 pF

(6) The time required for the output to reach a stable level following a change in the control voltage from +1.0 V to + 0.5 V. ⑦No condensation

SENSITIVITY ADJUSTMENT METHOD



MICRO PMT MODULE H12404/H12405 SERIES

The H12404/H12405 series are high sensitivity photosensor modules that contain a Micro PMT, a voltage divider circuit, and a high-voltage power supply circuit and amplifier circuit. These modules can be easily operated with a low voltage supply.



▲Left: H12405 series Right: H12404 series

(at +25 °C)

PRODUCT VARIATIONS

Type No.	Spectral response	Photocathode material	Features
H12404 / H12405	300 nm to 650 nm	Bialkali	for visible range
H12404-01 / H12405-01	300 nm to 850 nm	Multialkali	for visible to near IR range
H12404-20 / H12405-20	300 nm to 920 nm	Extended red multialkali	for visible to near IR range

SPECIFICATIONS

	Parameter		H12404 / H12405	H12404-01 / H12405-01	H12404-20 / H12405-20	Unit
Peak sensi	tivity wavelength		4	20	630	nm
Effective ar	ea			$3(X) \times 1(Y)$		mm
Window ma	aterial			Borosilicate glass		—
Dynode nu	mber of stages			12		—
Input voltag	je			±4.5 to ±5.5		V
Maximum i	nput voltage			±5.5		V
Maximum i	nput current 1			+23.5 / -3.5		mA
Maximum a	average output signal current		-	+4 (Load resistance 10 kΩ	2)	V
Maximum o	control voltage			+1.15		V
Recommer	ded control voltage adjustment	range	+0.5 to +1.0	+0.5 t	o +1.1	V
Control volt	age input impedance			1		MΩ
	Luminous sensitivity	Min.	50	100	300	uA/lm
		Тур.	80	200	400	p., e
Cathode	Blue sensitivity index (CS 5-58)	Тур.	8.0	_	_	—
	Red / White ratio	Тур.	—	0.2	0.45	
	Radiant sensitivity [©]	Тур.	80	62	60	mA/W
	Luminous sensitivity ³	Min.	3.0 × 10 ⁷	1.5 × 10 ⁷	3.0 × 10 ⁷	V/Im
		Тур.	1.6 × 10 ⁸	7.0 × 10 ⁷	1.0 × 10 ⁸	•/
Anode ^②	Radiant sensitivity 23	Тур.	160	21	15	V/nW
	Voltage output depending	Тур.	(0.3	0.6	mV
	on PMT dark current 34	Max.		3	6	
PMT gain		Тур.	2.0×10^{6}	3.5 × 10⁵	2.5 × 10 ⁵	—
Frequency	bandwidth		DC to 20 kHz			—
Current-to-	voltage conversion factor			1		V/µA
Output offset voltage Typ.			±1		mV	
Ripple noise ³⁵ (peak to peak) Max.		1.5			mV	
Settling tim	e ⁽⁶⁾	Max.		10		S
Operating a	ambient temperature 7		+5 to +50			°C
Storage ter	nperature 7			-20 to +50		°C
Weight			44 (H1	2404 series), 54 (H12405	i series)	g

①At ±5 V input voltage, +0.9 V control voltage, and output current equal to dark current ②Measured at the peak sensitivity wavelength

③+0.9 V control voltage ④After 30 minutes storage in darkness.

(5)Cable RG-174/U, Cable length 450 mm, Load resistance=1 M Ω , Load capacitance=22 pF

©The time required for the output to reach a stable level following a change in the control voltage from +1.0 V to + 0.5 V. ⑦No condensation

SENSITIVITY ADJUSTMENT METHOD



Characteristics

Dark current

A small amount of current is output from a photomultiplier tube even when operated in a completely dark state. This output current is called the anode dark current, and the resulting noise is a critical factor in determining the lower detection limit of photomultiplier tubes. The graph on the right shows typical dark current of a Micro PMT versus the supply voltage.



Output waveform

Photomultiplier tubes are photosensors with extremely high speeds. The figure on the right shows an output waveform example of a Micro PMT operating at an anodeto-cathode voltage of -900 V, measured with pulsed light (pulse width: 70 ps) that is sufficiently shorter than the response time of the PMT. This anode output pulse has a rise time of 1.2 ns and a fall time of 1.7 ns.



T.T.S. (transit time spread)

The time interval between the arrival of light at the photocathode and the instant when the anode output pulse reaches its peak amplitude is called the electron transit time.

The T.T.S. (transit time spread) indicates the fluctuations of the electron transit time measured when the photocathode is fully illuminated with single photons, and is defined as the FWHM of the histogram of the fluctuations. A typical T.T.S. of Micro PMT is 1.3 ns.



Pulse linearity

When an intense light pulse enters the photocathode of a photomultiplier tube, a large current flows in the latter dynode stages and increases the space charge density, causing current saturation. This causes the anode output to deviate from the ideal linearity. The figure below is a comparison of the pulse linearity between H1240x series and H14066 series. The pulse linearity for H14066 series is apparently improved compared with H1240x series due to the dynode structure change.



Ripple noise

The oscillator circuit used in high-voltage power supplies in photomultiplier tube modules induces noise into the signal input due to oscillation. This induction noise is referred to as ripple. The ripple can be observed on an oscilloscope along the baseline in a low voltage range by feeding the output signal to the oscilloscope input while no light is incident on the modules. For example, under conditions where the load resistance is 1 M Ω and the load capacitance is 22 pF, you will see a signal with an output near 200 V and a frequency of approximately 220 kHz.



4 (s/div.)

Uniformity

This uniformity is the variation of sensitivity with respect to the incident light position on the photocathode. The figure on the right shows an example of anode output measured by scanning a light spot of 1 mm diameter at 400 nm wavelength over the photocathode surface of a Micro PMT at a pitch of 0.1 mm in the X-axis and Y-axis directions. The output indicates relatively good uniformity.



(mV/div.)



Temperature characteristics

The anode sensitivity of photomultiplier tubes is affected by the ambient temperature. Temperature characteristics for anode sensitivity are wavelength-dependent, and the temperature coefficient generally fluctuates from a negative value to a positive value near the long wavelength limit. The figure on the right shows temperature coefficient data of micro PMT with a bialkali photocathode and multialkali photocathode as a function of wavelength. The temperature coefficient for both photocathodes is approximately -0.3 %/C at a wavelength around 500 nm.

Magnetic characteristics

An external magnetic field deviates the photoelectrons traveling in a photomultiplier tube from their normal trajectories, causing a loss of gain. The extent of the loss of gain depends on the direction of the magnetic field. The figure on the right shows how magnetic fields affect the output of a Micro PMT. It is seen that the magnetic field in the Z direction most affects the output. Terrestrial magnetism which is less than 0.1 mT will have almost no effect on the output.





MICRO PMT PHOTON COUNTING HEAD H12406 SERIES

The H12406 series is a photon counting head that contain a Micro PMT, a highvoltage power supply circuit and a photon counting circuit.

This photon counting head can be easily operated with a low voltage supply.



PRODUCT VARIATIONS

Type No.	Spectral response	Photocathode material	Features
H12406	300 nm to 650 nm	Bialkali	for visible range
H12406-01	300 nm to 850 nm	Multialkali	for visible to near IR range
H12406-20	300 nm to 920 nm	Extended red multialkali	for visible to near IR range

SPECIFICATIONS

at SPECIFICATIONS (at						(at +25 °C)
Parameter			H12406	H12406-01	H12406-20	Unit
Peak sensitivity wavelength			42	20	630	nm
Effective area				$3(X) \times 1(Y)$		mm
Window material				Borosilicate glass		
Dynode number of s	stages			12		
Input voltage				+4.75 to +5.25		V
Max. Input voltage				+6		V
Max. Input current	1			40		mA
		300 nm	1.7 × 10⁵	2.1 × 10⁵	4.4×10^{4}	
		400 nm	3.6 × 10⁵	2.7 × 10⁵	6.6 × 10 ⁴	
		500 nm	2.6 × 10⁵	2.3 × 10⁵	2.1 × 10 ⁵	
Count sensitivity	Тур.	600 nm	4.3×10^{4}	1.7 × 10⁵	2.6 × 10 ⁵	s⁻¹⋅pW⁻¹
		700 nm	1.4 × 10 ²	9.6 × 104	2.1 × 10 ⁵	_
		800 nm		2.1 × 104	1.2 × 10 ⁵	
		900 nm		—	3.9×10^{3}	
Count linearity 1			5.0 × 10 ⁶			S ⁻¹
Dark count ²		Тур.	10	100	500	e-1
		Max.	50	500	2500	
Pulse-pair resolution	า		20			ns
Output pulse width			10			ns
Output pulse height		Min.	+2.0			V
(at load resistance 5	50 Ω)	Тур.	+2.2			v
Recommended load	l resistance			50		Ω
Signal output logic				Positive logic		
Excessive light	Excessive light incident	Min.		+3.5		V
detection output ^③ Normally Max.			+0.5		V	
Operating ambient t	emperature ④		+5 to +50			°C
Storage temperature	e ⁽⁴⁾		-20 to +50			°C
Weight				46		g

 $\textcircled{1}\label{eq:Random pulse}$ at 10% count loss

②After 30 minute storage in darkness

3Load resistance 10 k Ω ④No condensation

COUNT SENSITIVITY



BLOCK DIAGRAM



Characteristics

Dark count

Some dark current pulses are generated in a photomultiplier tube during operation even if no light is incident on it. These dark current pulses are amplified by an amplifier and then only those dark pulses with a height exceeding a certain discriminator threshold are output through a pulse shaper. This output, expressed in counts per second (s⁻¹), is the dark count and indicates the lower limit of signal detection.



Output waveform

Output waveforms are positive logic signals. The figure on the right shows output waveforms measured with and without a load resistance of 50 Ω . Since photon counting head handles high-speed signals, a 50 Ω impedance cable is usually connected between a photon counting head and external device, and the input impedance of the external device should also preferably be 50 Ω .



OUTPUT COUNT

+4 V

1011

EXCESSIVE LIGHT

RELATIVE INPUT LIGHT

DETECTION OUTPUT

Count linearity and excessive light detection characteristics

In a random light input event, when the light level increases and exceeds a certain level, the output pulses begin to overlap each other and the count value is no longer proportional to the light level. As the light level further increases causing more pulses to overlap, the number of output pulses gradually saturates and then begins to decrease and eventually reaches 0. Count linearity is specified as the count value at which a 10 % loss occurs in the counted value compared to the theoretical value.

If the incident light level largely exceeds the count linearity, a signal (4.0 V) is output to indicate an excessive light input.

Count rate correction

When the number of pulses measured by photon counting exceeds 10^6 s⁻¹, counting errors begin to occur due to pulse overlap. One method for improving the count linearity utilizes a correction formula to find the approximate values. The graph on the right shows improved count linearity characteristics obtained by using a correction formula to find the approximate values.



106 107 108 109 1010

105

1010

10

10

10

106

10⁵

10

103

COUNT RATE (s-1)

Linearity correction formula $N = \frac{M}{1-Mt} \qquad \begin{array}{c} N: \text{ real count rate (s}^{-1}) \\ M: \text{ measured count rate (s}^{-1}) \\ t: \text{ pulse pair-resolution (s)} \end{array}$

* Micro PMT photon counting head H12406 series do not have the function to automaticlly output a correction value.

DIMENSIONAL OUTLINES (Unit: mm)

MICRO PMT ASSEMBLY

■ H12400 Series







MICRO PMT MODULE



MICRO PMT MODULE

H14066 Series



MICRO PMT MODULE

■ H12404 Series

SIGNAL OUTPUT



: RG-174/U

Weight: 44 g

TPMOA0109EA

MICRO PMT MODULE



H12402/H12403/H12404/H12405





DIMENSIONAL OUTLINES (Unit: mm)

MICRO PMT PHOTON COUNTING HEAD

■ H12406 Series





LOW VOLTAGE INPUT (+5 V) : UL1430 AWG26 (RED) GND : UL1430 AWG26 (BLACK) OVER LIGHT DETECTION OUTPUT: UL1430 AWG26 (BLUE) SIGNAL OUTPUT : RG-174/U Weight: 46 g



OPTION: OPTIONAL FIBER ADAPTER (sold separately)





RAMANATSU RAMANATSU GAZIO1A SNI ABCI 234 UNOE NURPH UNOE NURPH

HIGH VOLTAGE POWER SUPPLY C14210-14 0.4 W output 1100 V / 0.4 mA

The C14210-14 is the world's smallest surface-mount high voltage power supply module with a stabilizing circuit for photomultiplier tubes.

That is suitable for operating a H12400 series, which can reflow mounting.

Parameter			Value	
Input voltage range (VDD)			+3.0 to +5.0	V
Innut ourrent (1)	with no load	Тур.	40	
	with full load	Тур.	235	mA
Specification guaranteed output	voltage range)	-200 to -1100	V
Output current		Max.	0.4	mA
Output voltage rise time ²			150	ms
Line regulation Typ.		Тур.	±0.01	%
Load regulation Typ.		Тур.	±0.01	%
Temperature coefficient		Тур.	±0.01	%/°C
Ripple / Noise (p-p) ³		Тур.	50	mV
Operating ambient temperature	5		0 to +50	°C
Weight			4	g
Dimensions (W \times H \times D)			15 × 7 × 15	mm
Protective functions			Short circuit in output / Continuous overloading / Excessive controlling voltage input	

(1): VDD=+3 V, at maximum output voltage and current

②: Rise time (0 %→99 %)

3:5 kHz or more

(4): At ambient humidity below 80 % (no condensation)



HIGH VOLTAGE POWER SUPPLY C10940 SERIES 0.7 W output 1200 V / 0.6 mA

The C10940 series is a high voltage power supply module developed for compact size and high performance. This is designed to mount on a printed circuit making them suitable for use with a H12400 series Micro PMT assembly. Besides high performance and low power consumption, a variety of protective functions are also included.

Parameter			C10940-03	C10940-03-R2*	C10940-53	C10940-53-R2*	Unit
Input voltage (VDD)			+5.0 ± 0.5				V
Input current ^①	with no load	Тур.	60				mA
	with full load	Тур.	230				
Specification guaranteed output voltage range		2	-200 to -1200 +200 to +1200			V	
Output current		Max.	0.6				mA
Line regulation ¹³		Тур.	±0.02				%
Load regulation ¹		Тур.	±0.01				%
Ripple / Noise (p-p) 13		Тур.	50				mV
Output voltage rise time (Rise time 0 %→99 %) ⁽¹⁾		Тур.	120	300	120	300	ms
Temperature coefficient ⁽¹⁾			±0.01				%/°C
Operating ambient temperature ¹³			0 to +50				°C
Weight		7.7				g	
Dimensions (W \times H \times D)			15 × 18 × 15				mm
Protective functions		Units protected against reversed power input, reversed / excessive controlling voltage input, continuous overloading / short circuit output					

①: At maximum output voltage

2: The voltage from 0 V to -200 V/+200 V can be output but all characteristics are not necessarily satisfied.

3: At maximum output current

(4): No condensation

* -R2 type: RS-485 control





POWER SUPPLY FOR PMT MODULE C10709

The C10709 is a power supply unit designed to operate a PMT module. This unit supplies both drive voltage and control voltage, making it ideal for operating the H12402 series, H12403 series, H12404 series, H12405 series and H14066 series Micro PMT modules.

▲C10709



AMPLIFIER UNITS

These amplifier units convert the signal current input from a photomultiplier tube into a voltage output. Please select the desired type with a frequency range and current-to-voltage conversion factor that match your applications.



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HAMAMATSU PHOTONICS K.K. www.hamamatsu.com

Electron Tube Division

314-5, Shimokanzo, Iwata City, Shizuoka Pref., 438-0193, Japan, Telephone: (81)539/62-5248, Fax: (81)539/62-2205

U.S.A.: Hamanatsu Croporation: 360 Foothill Road, Bridgewater, NJ 08607, U.S.A.; Telephone: (1)903-902-906, Fax: (1)908-231-1218. E-mail: usa@hamamatsu.com
Germany: Hamamatsu Photonics Deutschland GmbH.: Arzbergerstr. 10, D-82211 Herrsching am Ammersee, Germany, Telephone: (49)8152-375-0, Fax: (49)8152-265-8. E-mail: info@hamamatsu.de
France: Hamamatsu Photonics Deutschland GmbH.: Arzbergerstr. 10, D-82211 Herrsching am Ammersee, Germany, Telephone: (49)8152-375-0, Fax: (49)8152-265-8. E-mail: info@hamamatsu.de
France: Hamamatsu Photonics Duck Limited: 2 Howard Court, 10 Tewin Road, Welwyn Garden City, Hertfordshire ALT 18W, UK, Telephone: (4)1707-2945777. E-mail: info@hamamatsu.co.uk
North Europe: Hamamatsu Photonics Norden AB: Torshamnsgatan 35 16440 Kista, Sweden, Telephone: (4)8-509 031 00, Fax: (49)8-509 031 01. E-mail: info@hamamatsu.se
Italy: Hamamatsu Photonics (Italia S.r.L.: Strada della Moia, 1 int. 6, 20020 Arese (Milano), Italy, Telephone: (4)902-93 58 17 33, Fax: (39)02-93 58 17 41 E-mail: info@hamamatsu.se
Italy: Hamamatsu Photonics Taiwan Co., Ltd: 1201 Tower B, Jaming Center, 27 Dongsanhuan Beliu, Chaoyang District, Hoinchu, 300, Taiwan R.O.C. Telephone: (86)3-659-0080, Fax: (86)3-659-0081 E-mail: info@hamamatsu.com.th